74HC4053; 74HCT4053 Triple 2-channel analog multiplexer/demultiplexer Rev. 9 — 10 February 2016 Prod

Product data sheet

General description

The 74HC4053; 74HCT4053 is a triple single-pole double-throw analog switch (3x SPDT) suitable for use in analog or digital 2:1 multiplexer/demultiplexer applications. Each switch features a digital select input (Sn), two independent inputs/outputs (nY0 and nY1) and a common input/output (nZ). A digital enable input (E) is common to all switches. When E is HIGH, the switches are turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

Features and benefits 2.

- Wide analog input voltage range from –5 V to +5 V
- Complies with JEDEC standard no. 7A
- Low ON resistance:
 - 80 Ω (typical) at $V_{CC} V_{EE} = 4.5 \text{ V}$
 - 70 Ω (typical) at $V_{CC} V_{EE} = 6.0 \text{ V}$
 - 60 Ω (typical) at $V_{CC} V_{EE} = 9.0 \text{ V}$
- Logic level translation: to enable 5 V logic to communicate with ±5 V analog signals
- Typical 'break before make' built-in
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

Applications

- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating

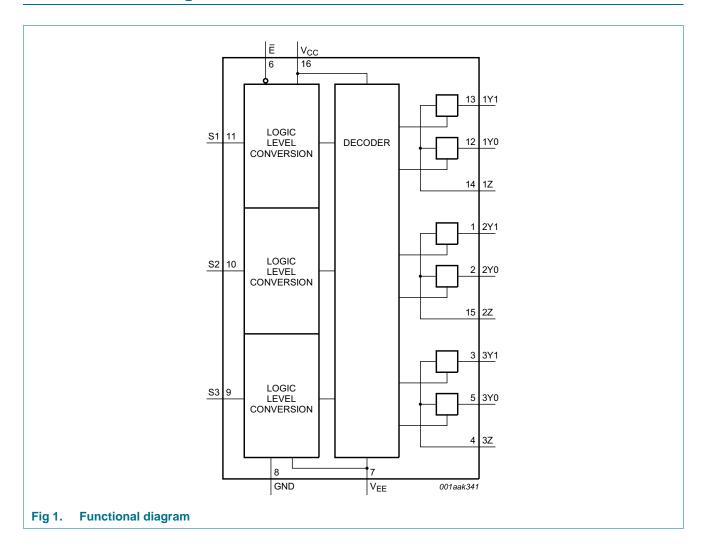


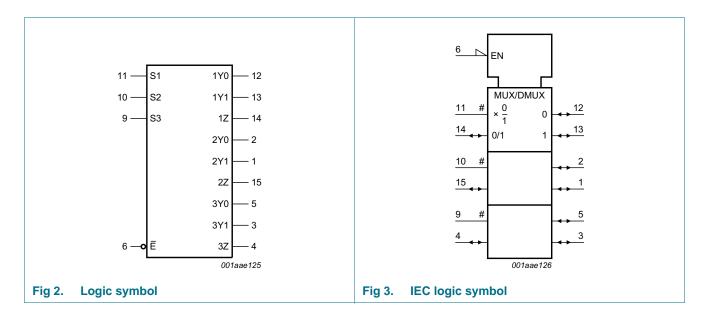
4. Ordering information

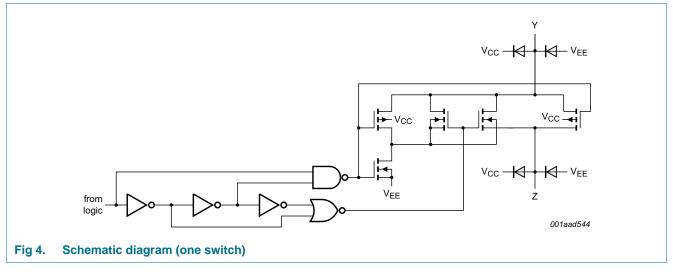
Table 1. Ordering information

Type number	Package				
	Temperature range	Name	Description	Version	
74HC4053D	−40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1	
74HCT4053D			body width 3.9 mm		
74HC4053DB	−40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads;	SOT338-1	
74HCT4053DB			body width 5.3 mm		
74HC4053PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1	
74HCT4053PW			body width 4.4 mm		
74HC4053BQ	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very	SOT763-1	
74HCT4053BQ			thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm		

5. Functional diagram



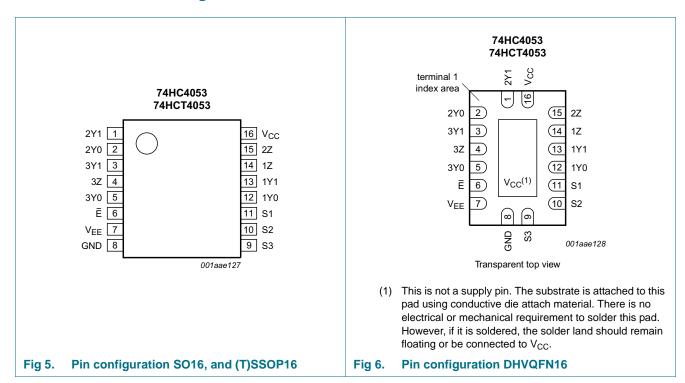




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6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Table 2: Till decomption		
Symbol	Pin	Description
Ē	6	enable input (active LOW)
V _{EE}	7	supply voltage
GND	8	ground supply voltage
S1, S2, S3	11, 10, 9	select input
1Y0, 2Y0, 3Y0	12, 2, 5	independent input or output
1Y1, 2Y1, 3Y1	13, 1, 3	independent input or output
1Z, 2Z, 3Z	14, 15, 4	common output or input
V _{CC}	16	supply voltage

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7. Functional description

Table 3. Function table [1]

Inputs		Channel on
E	Sn	
L	L	nY0 to nZ
L	Н	nY1 to nZ
Н	X	switches off

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to $V_{SS} = 0 \text{ V (ground)}$.

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage	[1]	-0.5	+11.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{SK}	switch clamping current	$V_{SW} < -0.5 \text{ V or } V_{SW} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{SW}	switch current	$-0.5 \text{ V} < \text{V}_{\text{SW}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I _{EE}	supply current		-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-	-50	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	SO16, (T)SSOP16, and DHVQFN16 package	-	500	mW
Р	power dissipation	per switch	-	100	mW

^[1] To avoid drawing V_{CC} current out of terminal nZ, when switch current flows into terminals nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no V_{CC} current will flow out of terminals nYn, and in this case there is no limit for the voltage drop across the switch, but the voltages at nYn and nZ may not exceed V_{CC} or V_{EE} .

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	74HC4053			74HCT4053			Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC} supply voltage	see <u>Figure 7</u> and <u>Figure 8</u>								
		V _{CC} – GND	2.0	5.0	10.0	4.5	5.0	5.5	V
		$V_{CC} - V_{EE}$	2.0	5.0	10.0	2.0	5.0	10.0	V
VI	input voltage		GND	-	V _{CC}	GND	-	V _{CC}	V
V_{SW}	switch voltage		V _{EE}	-	V _{CC}	V _{EE}	-	V _{CC}	V

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^[2] For SO16 packages: above 70 °C the value of P_{tot} derates linearly with 8 mW/K. For SSOP16 and TSSOP16 packages: above 60 °C the value of P_{tot} derates linearly with 5.5 mW/K. For DHVQFN16 packages: above 60 °C the value of P_{tot} derates linearly with 4.5 mW/K.

 Table 5.
 Recommended operating conditions ...continued

Symbol Parameter		Conditions	Conditions 74HC4053		74	Unit			
			Min	Тур	Max	Min	Тур	Max	
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV input transition rise and fall	input transition rise and fall	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
	rate	$V_{CC} = 4.5 \text{ V}$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V
		$V_{CC} = 10.0 \text{ V}$	-	-	31	-	-	-	ns/V

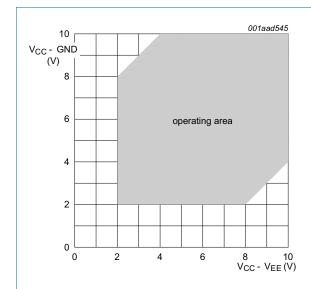


Fig 7. Guaranteed operating area as a function of the supply voltages for 74HC4053

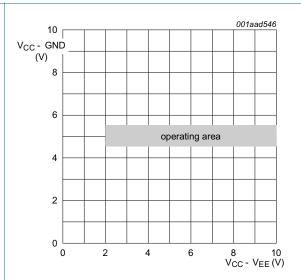


Fig 8. Guaranteed operating area as a function of the supply voltages for 74HCT4053

10. Static characteristics

Table 6. R_{ON} resistance per switch for 74HC4053 and 74HCT4053

 $V_I = V_{IH}$ or V_{IL} ; for test circuit see Figure 9.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

For 74HC4053: V_{CC} – GND or V_{CC} – V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

For 74HCT4053: V_{CC} – GND = 4.5 V and 5.5 V, V_{CC} – V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 25	°C						
R _{ON(peak)}	ON resistance (peak)	$V_{is} = V_{CC}$ to V_{EE}					
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 100 \mu\text{A}$	<u>[1]</u>	-	-	- 180 160 130 - 140 120 105 - 160 140 120 - - - -	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	100	180	Ω
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	90	160	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	70	- 180 160 130 - 140 120 105 - 160 140 120 	Ω
R _{ON(rail)}	ON resistance (rail)	$V_{is} = V_{EE}$				100	
ΔR _{ON} C		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 100 \mu\text{A}$	<u>[1]</u>	-	150	-	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$	10 V; I _{SW} = 1000 μA	Ω			
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	70	120	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	60	105	Ω
		$V_{is} = V_{CC}$					
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 100 \mu\text{A}$	<u>[1]</u>	-	150	-	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	90	160	Ω
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	80	140	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	65	120	Ω
ΔR _{ON}	ON resistance mismatch	$V_{is} = V_{CC}$ to V_{EE}				00	
	between channels	V _{CC} = 2.0 V; V _{EE} = 0 V	<u>[1]</u>	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	9	- 180 160 130 - 140 120 105 - 160 140 120 - - -	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V		-	8		Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$		-	6	-	Ω
$T_{amb} = -4$	0 °C to +85 °C	·	,				
R _{ON(peak)}	ON resistance (peak)	$V_{is} = V_{CC}$ to V_{EE}					
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 100 \mu\text{A}$	<u>[1]</u>	-	-	-	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	225	Ω
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	200	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	165	Ω

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R_{ON} resistance per switch for 74HC4053 and 74HCT4053 ...continued

 $V_I = V_{IH}$ or V_{IL} ; for test circuit see <u>Figure 9</u>.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

For 74HC4053: V_{CC} – GND or V_{CC} – V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V. For 74HCT4053: V_{CC} – GND = 4.5 V and 5.5 V, V_{CC} – V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{ON(rail)}	ON resistance (rail)	$V_{is} = V_{EE}$				- 175 150 130 - 200 175 150 - 270 240 195	
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 100 \mu\text{A}$	[1]	-	Ω		
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	- 175 150 130 - 200 175 150 - 270 240 195 - 210 180 160	Ω
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	150	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	- 175 150 130 - 200 175 150 - 270 240	Ω
		$V_{is} = V_{CC}$					
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 100 \mu\text{A}$	[1]	-	-	-	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	200	Ω
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	175	Ω
V _{CC} =	$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	150	Ω	
$T_{amb} = -4$	0 °C to +125 °C						
R _{ON(peak)}	ON resistance (peak)	V _{is} = V _{CC} to V _{EE}					
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 100 \mu\text{A}$	<u>[1]</u>	-		-	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	270	Ω
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	240	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	195	Ω
R _{ON(rail)}	ON resistance (rail)	$V_{is} = V_{EE}$			-		
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 100 \mu\text{A}$	<u>[1]</u>	-	-	-	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	210	Ω
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	180	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	160	Ω
		$V_{is} = V_{CC}$					
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 100 \mu\text{A}$	[1]	-	-	-	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	240	Ω
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	210	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	-	180	Ω

^[1] When supply voltages (V_{CC} - V_{EE}) near 2.0 V the analog switch ON resistance becomes extremely non-linear. When using a supply of 2 V, it is recommended to use these devices only for transmitting digital signals.

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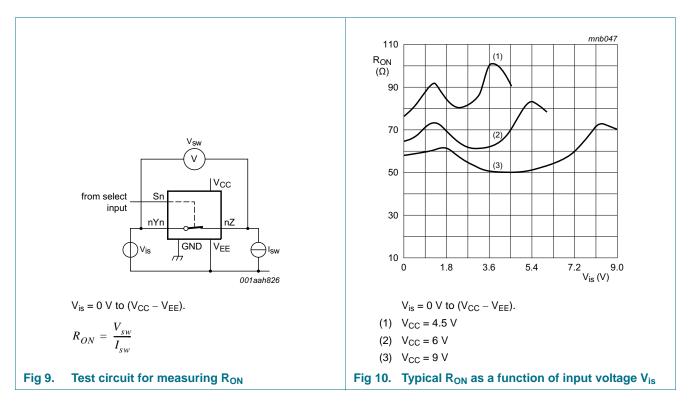


Table 7. Static characteristics for 74HC4053

Voltages are referenced to GND (ground = 0 V).

V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 V_{os} is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C					
V _{IH}	HIGH-level input	V _{CC} = 2.0 V	1.5	1.2	-	V
	voltage	V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
		V _{CC} = 9.0 V	6.3	4.7	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	V
		V _{CC} = 4.5 V	-	2.1	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	V
		V _{CC} = 9.0 V	-	4.3	2.7	V
I _I	input leakage current	$V_{EE} = 0 \text{ V}; V_{I} = V_{CC} \text{ or GND}$				
		V _{CC} = 6.0 V	-	-	±0.1	μΑ
		V _{CC} = 10.0 V	-	-	±0.2	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Figure 11$				
		per channel	-	-	±0.1	μΑ
		all channels	-	-	±0.1	μΑ
I _{S(ON)}	ON-state leakage current	$V_I = V_{IH} \text{ or } V_{IL}; V_{SW} = V_{CC} - V_{EE};$ $V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; \text{ see } \frac{\text{Figure 12}}{\text{Figure 12}}$	-	-	±0.1	μΑ

Table 7. Static characteristics for 74HC4053 ...continued

Voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 V_{os} is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CC}	supply current	$V_{EE} = 0 \text{ V}; V_{I} = V_{CC} \text{ or GND}; V_{is} = V_{EE} \text{ or } V_{CC};$ $V_{os} = V_{CC} \text{ or } V_{EE}$				
		V _{CC} = 6.0 V	-	-	8.0	μΑ
		V _{CC} = 10.0 V	-	-	16.0	μА
Cı	input capacitance		-	3.5	-	pF
C _{sw}	switch capacitance	independent pins nYn	-	5	-	pF
		common pins nZ	-	8	-	pF
T _{amb} = -40	0 °C to +85 °C			1	1	
V _{IH}	HIGH-level input	V _{CC} = 2.0 V	1.5	-	-	V
	voltage	V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	-	0.5	V
	voltage	V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	- 1.8	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V
I _I	input leakage current	$V_{EE} = 0 \text{ V}; V_{I} = V_{CC} \text{ or GND}$				
		V _{CC} = 6.0 V	-	-	±1.0	μΑ
		V _{CC} = 10.0 V	-	-	±2.0	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Figure 11$				
		per channel	-	±1.0	μΑ	
		all channels	-	-	±1.0	μА
I _{S(ON)}	ON-state leakage current	$V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - V_{EE}$; $V_{CC} = 10.0$ V; $V_{EE} = 0$ V; see Figure 12	-	-	±1.0	μΑ
I _{CC}	supply current	$V_{EE} = 0 \text{ V}; V_{I} = V_{CC} \text{ or GND}; V_{is} = V_{EE} \text{ or } V_{CC};$ $V_{os} = V_{CC} \text{ or } V_{EE}$				
		V _{CC} = 6.0 V	-	-	80.0	μА
		V _{CC} = 10.0 V	-	-	160.0	μΑ
T _{amb} = -40	0 °C to +125 °C			•		
V _{IH}	HIGH-level input	V _{CC} = 2.0 V	1.5	-	-	V
	voltage	V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	-	0.5	V
	voltage	V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V

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Table 7. Static characteristics for 74HC4053 ... continued

Voltages are referenced to GND (ground = 0 V).

V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 V_{os} is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _I	input leakage current	V _{EE} = 0 V; V _I = V _{CC} or GND				
		V _{CC} = 6.0 V	-	-	±1.0	μΑ
		V _{CC} = 10.0 V	-	-	±2.0	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{see } Figure 11$				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±1.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - V_{EE}$; $V_{CC} = 10.0$ V; $V_{EE} = 0$ V; see Figure 12	-	-	±1.0	μА
I _{CC}	supply current	V_{EE} = 0 V; V_{I} = V_{CC} or GND; V_{is} = V_{EE} or V_{CC} ; V_{os} = V_{CC} or V_{EE}				
		V _{CC} = 6.0 V		-	160.0	μΑ
		V _{CC} = 10.0 V	-	-	320.0	μΑ

Table 8. Static characteristics for 74HCT4053

Voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 V_{os} is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C				ı	
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $V_{EE} = 0$ V	-	-	±0.1	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } \frac{\text{Figure } 11}{\text{Figure } 11}$				
		per channel		-	±0.1	μΑ
		all channels	-	-	±0.1	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Figure 12$	-	-	±0.1	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	8.0	μΑ
		$V_{CC} = 5.0 \text{ V}; V_{EE} = -5.0 \text{ V}$	-	-	16.0	μΑ
Δl _{CC}	additional supply current	per input; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $V_{EE} = 0 \text{ V}$	-	50	180	μА
Cı	input capacitance		-	3.5	-	pF
C _{sw}	switch capacitance	independent pins nYn	-	5	-	pF
		common pins nZ	-	8	-	pF

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Table 8. Static characteristics for 74HCT4053 ...continued

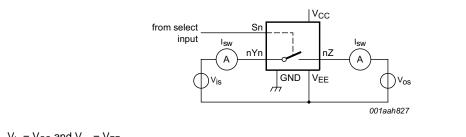
Voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 V_{os} is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
T _{amb} = -40	0 °C to +85 °C					1	
V_{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V	
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V	
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $V_{EE} = 0$ V	-	-	±1.0	μΑ	
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Figure 11$					
		per channel	-	-	±1.0	μΑ	
		all channels	-	-	±1.0	μΑ	
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } \frac{\text{Figure } 12}{\text{Figure } 12}$	$V_{\rm SW} = V_{\rm CC} - V_{\rm EE};$ see <u>Figure 12</u>				
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}					
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	80.0	μΑ	
		$V_{CC} = 5.0 \text{ V}; V_{EE} = -5.0 \text{ V}$	-	-	160.0	μΑ	
Δl _{CC}	additional supply current	per input; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $V_{EE} = 0 \text{ V}$	-	-	225	μΑ	
T _{amb} = -40	0 °C to +125 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V	
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V	
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $V_{EE} = 0$ V	-	-	±1.0	μΑ	
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Figure 11$					
		per channel	-	-	±1.0	μΑ	
		all channels	-	-	±1.0	μΑ	
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } \frac{\text{Figure } 12}{\text{Figure } 12}$	-	-	±1.0	μΑ	
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}					
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	160.0	μΑ	
		$V_{CC} = 5.0 \text{ V}; V_{EE} = -5.0 \text{ V}$	-	-	320.0	μΑ	
ΔI_{CC}	additional supply current	per input; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $V_{EE} = 0 \text{ V}$	-	-	245	μΑ	

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 $V_{is} = V_{CC}$ and $V_{os} = V_{EE}$. $V_{is} = V_{EE}$ and $V_{os} = V_{CC}$.

Fig 11. Test circuit for measuring OFF-state current

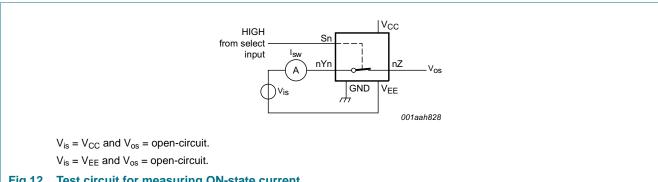


Fig 12. Test circuit for measuring ON-state current

11. Dynamic characteristics

Table 9. **Dynamic characteristics for 74HC4053**

GND = 0 V; $t_r = t_f = 6 \text{ ns}$; $C_L = 50 \text{ pF}$; for test circuit see Figure 15.

V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 13</u> [1]				
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	15	60	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	5	12	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	4	10	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	4	8	ns

Table 9. Dynamic characteristics for 74HC4053 ...continued

 $GND = 0 \text{ V}; t_r = t_f = 6 \text{ ns}; C_L = 50 \text{ pF}; \text{ for test circuit see } \underline{\text{Figure 15}}.$

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
on	turn-on time	\overline{E} to $V_{os};R_{L}=\infty\Omega;see\underline{Figure14}$	2]			
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	60	220	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	20	44	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	17	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	16	37	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	31	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see Figure 14	2]			
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	75	220	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	25	44	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	21	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	20	37	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	31	ns
off	turn-off time	\overline{E} to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	3]			
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	63	210	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	21	42	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	18	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	17	36	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	29	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	3]			
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	60	210	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	20	42	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	17	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	16	36	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	29	ns
C _{PD}	power dissipation capacitance	per switch; $V_I = GND$ to V_{CC}	4] _	36	-	pF
Γ _{amb} = –4	10 °C to +85 °C		,			'
pd	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 13</u>	1]			
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	75	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	15	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	13	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	10	ns

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 Table 9.
 Dynamic characteristics for 74HC4053 ...continued

 $GND = 0 \text{ V; } t_r = t_f = 6 \text{ ns; } C_L = 50 \text{ pF; for test circuit see } \underline{\text{Figure 15}}.$

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{on}	turn-on time	\overline{E} to $V_{os}; R_{L} = \infty \Omega; see \underline{Figure 14}$	[2]			
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	275	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	55	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	47	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	39	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see Figure 14	[2]			
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	275	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	55	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	47	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	39	ns
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see Figure 14	[3]			
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	265	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	53	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	45	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	36	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	[3]			
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	265	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	53	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	45	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	36	ns
T _{amb} = -4	10 °C to +125 °C				1	
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see Figure 13	[1]			
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	90	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	18	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	15	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	12	ns
t _{on}	turn-on time	\overline{E} to $V_{os};R_{L}=\infty\Omega;see\underline{Figure14}$	[2]			
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	330	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	66	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	56	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	47	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see Figure 14	[2]			
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	330	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	66	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	56	ns

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Table 9. Dynamic characteristics for 74HC4053 ...continued

GND = 0 V; $t_r = t_f = 6 \text{ ns}$; $C_L = 50 \text{ pF}$; for test circuit see <u>Figure 15</u>.

V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

Vos is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{off}	turn-off time	\overline{E} to V_{os} ; $R_L = 1 \text{ k}\Omega$; see $\underline{Figure 14}$				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	315	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	63	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	54	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	44	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	315	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	63	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	54	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	44	ns

- [1] t_{pd} is the same as t_{PHL} and t_{PLH}.
- [2] t_{on} is the same as t_{PZH} and t_{PZL} .
- [3] t_{off} is the same as t_{PHZ} and t_{PLZ} .
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

N = number of inputs switching;

 $\Sigma \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\} = sum \text{ of outputs};$

C_L = output load capacitance in pF;

C_{sw} = switch capacitance in pF;

 V_{CC} = supply voltage in V.

Table 10. Dynamic characteristics for 74HCT4053

GND = 0 V; $t_r = t_f = 6 \text{ ns}$; $C_L = 50 \text{ pF}$; for test circuit see Figure 15.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C				-	
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 13</u> [1]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	5	12	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	4	8	ns
t _{on} turr	turn-on time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see Figure 14				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	27	48	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	23	-	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	16	34	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	25	48	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	21	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	16	34	ns

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Table 10. Dynamic characteristics for 74HCT4053 ...continued

 $GND = 0 \text{ V}; t_r = t_f = 6 \text{ ns}; C_L = 50 \text{ pF}; \text{ for test circuit see } \underline{\textbf{Figure 15}}.$

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{off}	turn-off time	\overline{E} to V_{os} ; $R_L = 1 \text{ k}\Omega$; see $\underline{Figure 14}$	1			
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	24	44	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	20	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	31	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see <u>Figure 14</u>	[
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	22	44	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	19	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	31	ns
C_{PD}	power dissipation capacitance	per switch; $V_I = GND$ to $V_{CC} - 1.5 \text{ V}$	-	36	-	pF
$T_{amb} = -4$	0 °C to +85 °C					
t _{pd} propagation delay		V_{is} to V_{os} ; $R_L = \infty \Omega$; see Figure 13	1			
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	15	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	10	ns
t _{on}	turn-on time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see <u>Figure 14</u>	1			
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	60	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	43	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	1			
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	60	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	43	ns
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see <u>Figure 14</u>	1			
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	55	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	39	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	1			
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	55	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	39	ns
T _{amb} = -4	0 °C to +125 °C		'			
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see Figure 13	1			
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	18	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	12	ns
t _{on}	turn-on time	\overline{E} to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	1			
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	72	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	51	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	!			
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	72	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	51	ns

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Table 10. Dynamic characteristics for 74HCT4053 ...continued

GND = 0 V; $t_r = t_f = 6 \text{ ns}$; $C_L = 50 \text{ pF}$; for test circuit see <u>Figure 15</u>.

Vis is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see <u>Figure 14</u>				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	66	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	47	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14				
	$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$		-	-	66	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	47	ns

- [1] t_{pd} is the same as t_{PHL} and t_{PLH} .
- [2] ton is the same as tPZH and tPZL.
- [3] t_{off} is the same as t_{PHZ} and t_{PLZ} .
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \Sigma \{(C_L + C_{sw}) \times V_{CC}{}^2 \times f_o\} \text{ where: }$$

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

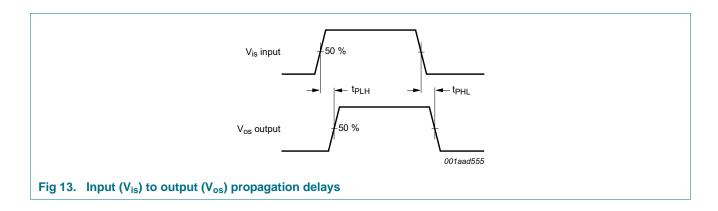
N = number of inputs switching;

 $\Sigma \{ (C_L + C_{sw}) \times V_{CC}^2 \times f_o \} = \text{sum of outputs};$

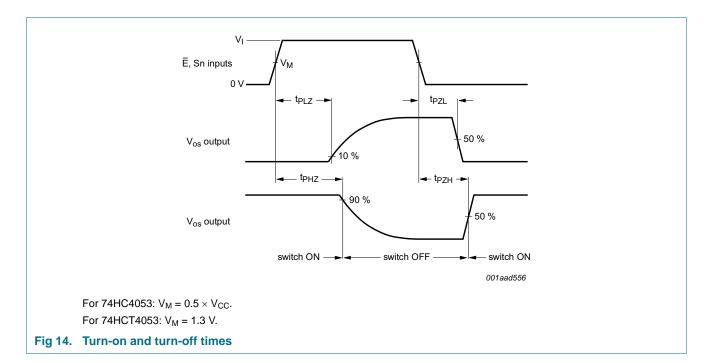
C_L = output load capacitance in pF;

C_{sw} = switch capacitance in pF;

 V_{CC} = supply voltage in V.



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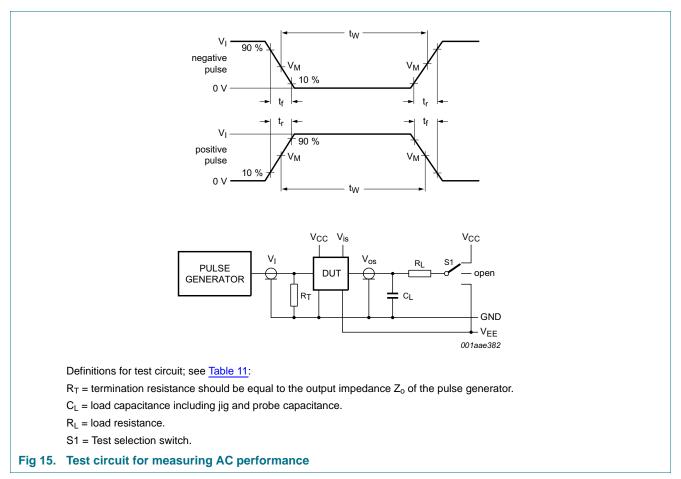


Table 11. Test data

Test	Input			Load	S1 position		
	VI	V _{is}	t _r , t _f	t _r , t _f		R _L	
			at f _{max}	other[1]			
t _{PHL} , t _{PLH}	[2]	pulse	< 2 ns	6 ns	50 pF	1 kΩ	open
t_{PZH},t_{PHZ}	[2]	V _{CC}	< 2 ns	6 ns	50 pF	1 kΩ	V _{EE}
t_{PZL}, t_{PLZ}	[2]	V _{EE}	< 2 ns	6 ns	50 pF	1 kΩ	V _{CC}

- [1] $t_r = t_f = 6$ ns; when measuring f_{max} , there is no constraint to t_r and t_f with 50 % duty factor.
- [2] V_I values:
 - a) For 74HC4053: $V_I = V_{CC}$
 - b) For 74HCT4053: $V_1 = 3 V$

11.1 Additional dynamic characteristics

Table 12. Additional dynamic characteristics

Recommended conditions and typical values; GND = 0 V; $T_{amb} = 25$ °C; $C_L = 50$ pF. V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input. V_{os} is the output voltage at pins nYn or nZ, whichever is assigned as an output.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
d _{sin}	sine-wave distortion	$f_i = 1 \text{ kHz}$; $R_L = 10 \text{ k}\Omega$; see Figure 16					
		$V_{is} = 4.0 \text{ V (p-p)}; V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$		-	0.04	-	%
		$V_{is} = 8.0 \text{ V (p-p)}; V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$		-	0.02	-	%
		$f_i = 10 \text{ kHz}$; $R_L = 10 \text{ k}\Omega$; see Figure 16					
		$V_{is} = 4.0 \text{ V (p-p)}; V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$		-	0.12	-	%
		$V_{is} = 8.0 \text{ V (p-p)}; V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$		-	0.06	-	%
α_{iso}	isolation (OFF-state)	$R_L = 600 \Omega$; $f_i = 1 MHz$; see Figure 17					
		$V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$	[1]	-	-50	-	dB
	$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	[1]	-	-50	-	dB	
Xtalk crosstalk	crosstalk	between two switches/multiplexers; $R_L = 600 \Omega$; $f_i = 1 MHz$; see Figure 18					
		V _{CC} = 2.25 V; V _{EE} = -2.25 V	[1]	-	-60	-	dB
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	[1]	-	-60	-	dB
V _{ct} crosstalk voltage		peak-to-peak value; between control and any switch; $R_L = 600 \ \Omega$; $f_i = 1 \ MHz$; \overline{E} or Sn square wave between V_{CC} and GND; $t_r = t_f = 6 \ ns$; see Figure 19					
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	110	-	mV
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$		-	220	-	mV
f _(-3dB)	-3 dB frequency response	$R_L = 50 \Omega$; see Figure 20					
		V _{CC} = 2.25 V; V _{EE} = -2.25 V	[2]	-	160	-	MHz
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	[2]	-	170	-	MHz

- [1] Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).
- [2] Adjust input voltage V_{is} to 0 dBm level at V_{os} for 1 MHz (0 dBm = 1 mW into 50 Ω).

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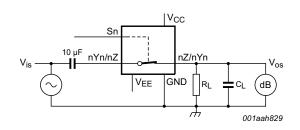
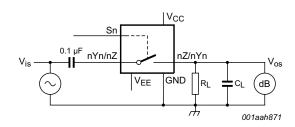
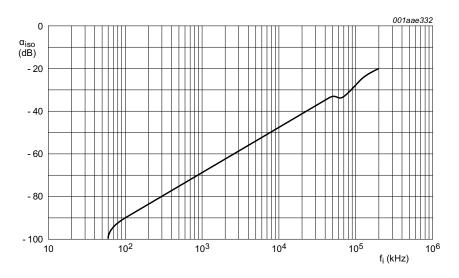


Fig 16. Test circuit for measuring sine-wave distortion



 V_{CC} = 4.5 V; GND = 0 V; V_{EE} = –4.5 V; R_L = 600 $\Omega;$ R_S = 1 $k\Omega.$

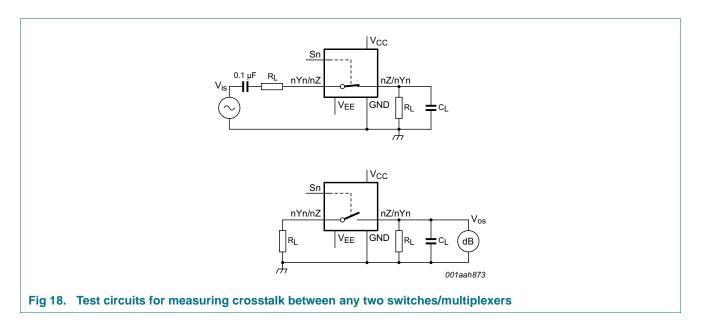
a. Test circuit

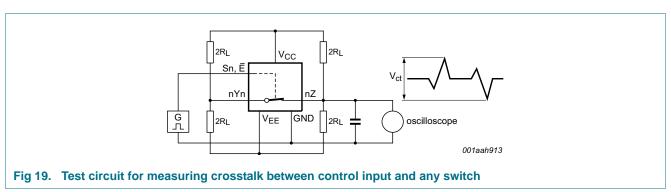


b. Isolation (OFF-state) as a function of frequency

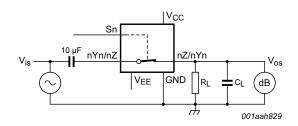
Fig 17. Test circuit for measuring isolation (OFF-state)

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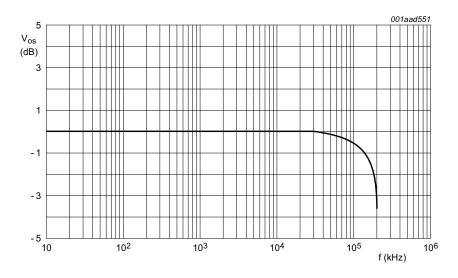


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 V_{CC} = 4.5 V; GND = 0 V; V_{EE} = –4.5 V; R_L = 50 $\Omega;$ R_S = 1 $k\Omega.$

a. Test circuit



b. Typical frequency response

Fig 20. Test circuit for frequency response

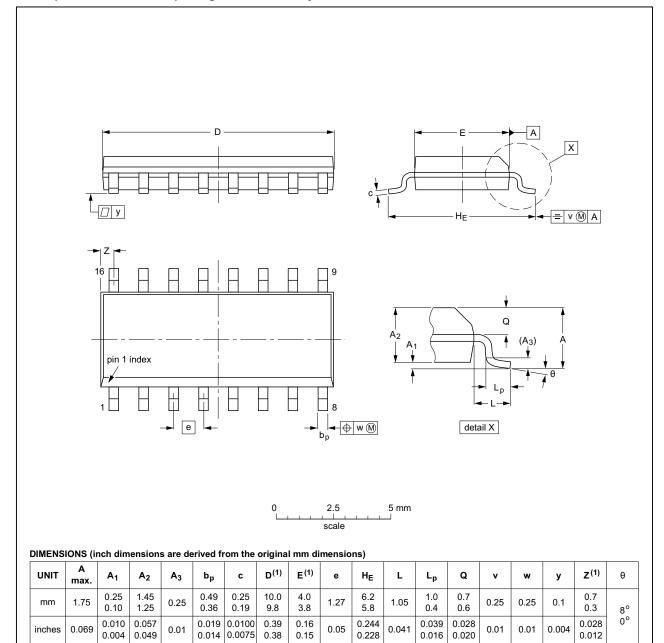
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12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

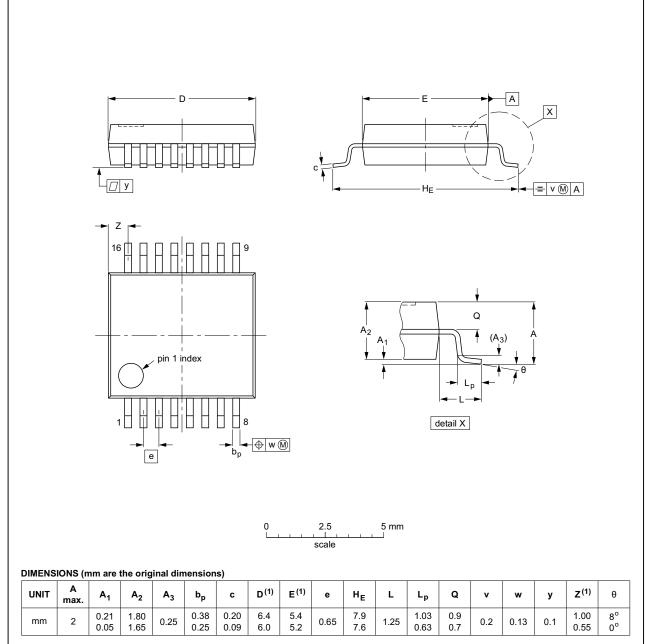
OUTLINE		REFER	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012			99-12-27 03-02-19

Fig 21. Package outline SOT109-1 (SO16)

74HC_HCT4053

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

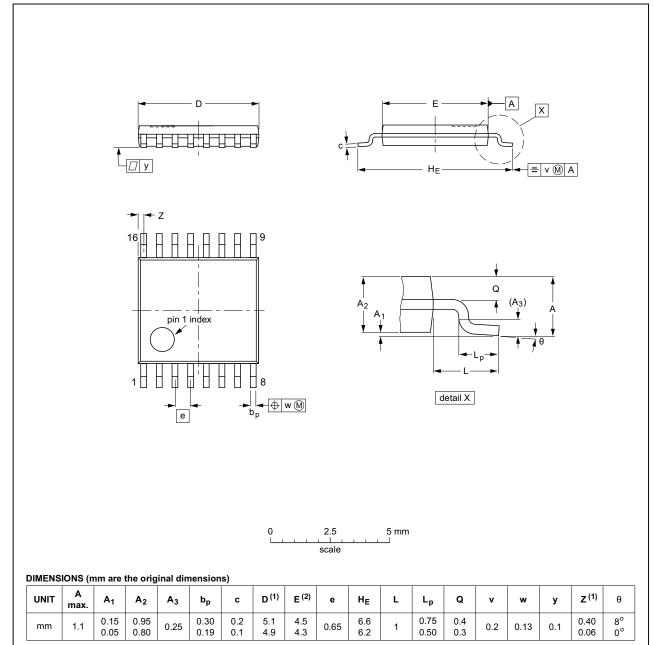
OUTLINE		REFER	REFERENCES			ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT338-1		MO-150				99-12-27 03-02-19

Fig 22. Package outline SOT338-1 (SSOP16)

74HC_HCT4053

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT403-1		MO-153				99-12-27 03-02-18

Fig 23. Package outline SOT403-1 (TSSOP16)

74HC_HCT4053

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

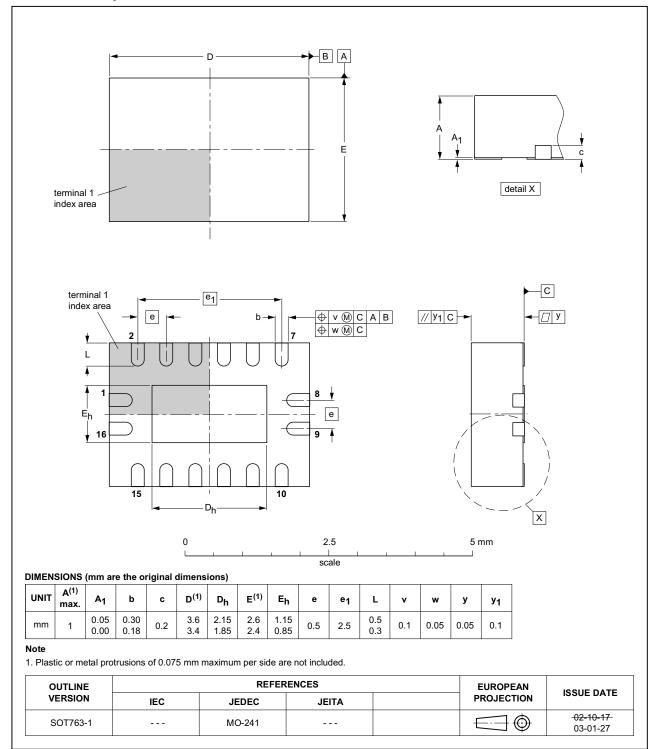


Fig 24. Package outline SOT763-1 (DHVQFN16)

74HC_HCT4053 All inform:

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13. Abbreviations

Table 13. Abbreviations

Acronym	Description	
CMOS	Complementary Metal-Oxide Semiconductor	
ESD	ElectroStatic Discharge	
HBM	Human Body Model	
MM	Machine Model	

14. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74HC_HCT4053 v.9	20160210	Product data sheet	-	74HC_HCT4053 v.8	
Modifications:	Type numbers 74HC4053N and 74HCT4053N (SOT38-4) removed.				
74HC_HCT4053 v.8	20120719	Product data sheet	-	74HC_HCT4053 v.7	
Modifications: • CDM added		o features.			
74HC_HCT4053 v.7	20111213	Product data sheet	-	74HC_HCT4053 v.6	
Modifications:	• Legal pages u	updated.			
74HC_HCT4053 v.6	20110511	Product data sheet	-	74HC_HCT4053 v.5	
74HC_HCT4053 v.5	20110118	Product data sheet	-	74HC_HCT4053 v.4	
74HC_HCT4053 v.4	20060509	Product data sheet	-	74HC_HCT4053 v.3	
74HC_HCT4053 v.3	20060315	Product data sheet	-	74HC_HCT4053_CNV v.2	
74HC_HCT4053_CNV v.2	19901201	Product specification	-	-	

15. Legal information

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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